

SPICE Device Model Si6913DQ Vishay Siliconix

Dual P-Channel 12-V (D-S) MOSFET

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS

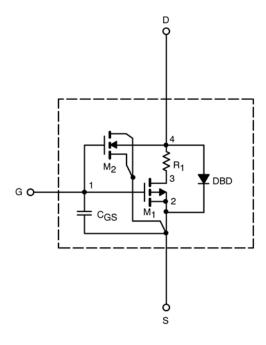
- · Apply for both Linear and Switching Application
- Accurate over the -55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the -55 to 125°C temperature ranges under the pulsed 0 to 4.5V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC



This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

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SPECIFICATIONS (T _J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	Symbol	Test Conditions	Simulated Data	Measured Data	Unit
Static					
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -400 \mu A$	0.81		V
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V}$	196		Α
Drain-Source On-State Resistance ^b	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -5.8 \text{ A}$	0.017	0.016	Ω
		$V_{GS} = -2.5 \text{ V}, I_{D} = -5 \text{ A}$	0.021	0.021	
		$V_{GS} = -1.8 \text{ V}, I_D = -4.4 \text{ A}$	0.029	0.029	
Forward Transconductance ^b	g _{fs}	$V_{DS} = -5 \text{ V}, I_{D} = -5.8 \text{ A}$	27	25	S
Diode Forward Voltage ^b	V_{SD}	$I_{S} = -1 \text{ A}, V_{GS} = 0 \text{ V}$	-0.78	-0.61	V
Dynamic ^a					
Total Gate Charge	Q_g	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -5.8 \text{ A}$	19	18.5	nC
Gate-Source Charge	Q_{gs}		2.7	2.7	
Gate-Drain Charge	Q_{gd}		5	5	
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = -6 V, R _L = 6 Ω I _D \cong -1 A, V _{GEN} = -4.5 V, R _G = 6 Ω	58	45	ns
Rise Time	t _r		39	80	
Turn-Off Delay Time	$t_{d(off)}$		134	130	
Fall Time	t _f		35	80	

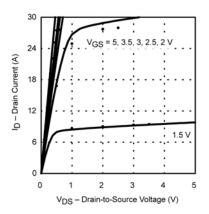
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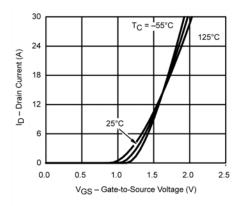
Notes a. Guaranteed by design, not subject to production testing. b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2\%.$

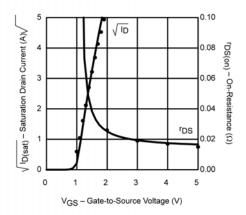


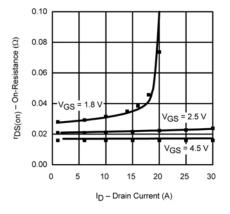
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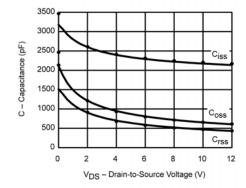
COMPARISON OF MODEL WITH MEASURED DATA (TJ=25°C UNLESS OTHERWISE NOTED)

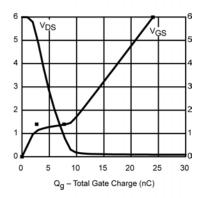












Note: Dots and squares represent measured data.

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Document Number: 91000 Revision: 18-Jul-08

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